LM78S40

LM78S40 Universal Switching Regulator Subsystem

Literature Number: SNVS021

National Semiconductor

April 1998

LM78S40
Universal Switching Regulator Subsystem

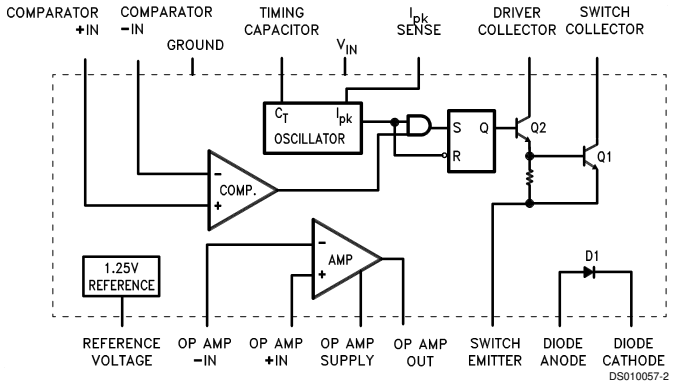
General Description

The LM78S40 is a monolithic regulator subsystem consisting of all the active building blocks necessary for switching regulator systems. The device consists of a temperature compensated voltage reference, a duty-cycle controllable oscillator with an active current limit circuit, an error amplifier, high current, high voltage output switch, a power diode and an uncommitted operational amplifier. The device can drive external NPN or PNP transistors when currents in excess of 1.5A or voltages in excess of 40V are required. The device can be used for step-down, step-up or inverting switching regulators as well as for series pass regulators. It features wide supply voltage range, low standby power dissipation, high efficiency and low drift. It is useful for any stand-alone, low part count switching system and works extremely well in battery operated systems.

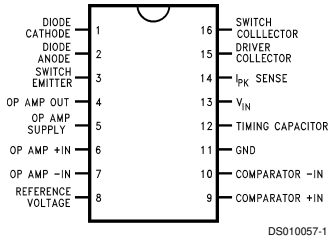
Features

- Step-up, step-down or inverting switching regulators
- Output adjustable from 1.25V to 40V
- Peak currents to 1.5A without external transistors
- Operation from 2.5V to 40V input
- Low standby current drain
- 80 dB line and load regulation
- High gain, high current, independent op amp
- Pulse width modulation with no double pulsing

Block and Connection Diagrams



16-Lead DIP



Top View

Ordering Information

Part Number	NS Package	Temperature Range
LM78S40J/883	J16A Ceramic DIP	–55˚C to +125˚C
LM78S40N	N16E Molded DIP	–40˚C to +125˚C
LM78S40CN	N16E Molded DIP	0˚C to +70˚C

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Storage Temperature Range	
Ceramic DIP	−65˚C to +175˚C
Molded DIP	−65˚C to +150˚C
Operating Temperature Range	
Extended (LM78S40J)	−55˚C to +125˚C
Industrial (LM78S40N)	−40˚C to +125˚C
Commercial (LM78S40CN)	0˚C to +70˚C
Lead Temperature	
Ceramic DIP (Soldering, 60 sec.)	300˚C
Molded DIP (Soldering, 10 sec.)	265˚C
Internal Power Dissipation (Note 2) (Note 3)	
16L-Ceramic DIP	1.50W
16L-Molded DIP	1.04W
Input Voltage from V_{IN} to GND	40V
Input Voltage from V^+ (Op Amp) to GND	40V
Common Mode Input Range (Comparator and Op Amp)	−0.3 to V+
Differential Input Voltage (Note 4)	±30V
Output Short Circuit Duration (Op Amp)	Continuous
Current from V_{REF}	10 mA
Voltage from Switch Collectors to GND	40V
Voltage from Switch Emitters to GND	40V
Voltage from Switch Collectors to Emitter	40V
Voltage from Power Diode to GND	40V
Reverse Power Diode Voltage	40V
Current through Power Switch	1.5A
Current through Power Diode	1.5A
ESD Susceptibility	(to be determined)

LM78S40
Electrical Characteristics (Note 5)

T_A = Operating temperature range, V_{IN} = 5.0V, V^+(Op Amp) = 5.0V, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
GENERAL CHARACTERISTICS						
I_{CC}	Supply Current (Op Amp Disconnected)	V_{IN} = 5.0V		1.8	3.5	mA
		V_{IN} = 40V		2.3	5.0	mA
I_{CC}	Supply Current (Op Amp Connected)	V_{IN} = 5.0V			4.0	mA
		V_{IN} = 40V			5.5	mA
REFERENCE SECTION						
V_{REF}	Reference Voltage	I_{REF} = 1.0 mA, Extend −55˚C < T_A < +125˚C, Comm 0 < T_A < +70˚C, Indus −40˚C < T_A < +85˚C	1.180	1.245	1.310	V
$V_{R\ LINE}$	Reference Voltage Line Regulation	V_{IN} = 3.0V to V_{IN} = 40V, I_{REF} = 1.0 mA, T_A = 25˚C		0.04	0.2	mV/V
$V_{R\ LOAD}$	Reference Voltage Load Regulation	I_{REF} = 1.0 mA to I_{REF} = 10 mA, T_A = 25˚C		0.2	0.5	mV/mA
OSCILLATOR SECTION						
I_{CHG}	Charging Current	V_{IN} = 5.0V, T_A = 25˚C	20		50	µA
I_{CHG}	Charging Current	V_{IN} = 40V, T_A = 25˚C	20		70	µA
I_{DISCHG}	Discharge Current	V_{IN} = 5.0V, T_A = 25˚C	150		250	µA
I_{DISCHG}	Discharge Current	V_{IN} = 40V, T_A = 25˚C	150		350	µA
V_{OSC}	Oscillator Voltage Swing	V_{IN} = 5.0V, T_A = 25˚C		0.5		V
t_{on}/t_{off}	Ratio of Charge/ Discharge Time			6.0		µs/µs
CURRENT LIMIT SECTION						
V_{CLS}	Current Limit Sense Voltage	T_A = 25˚C	250		350	mV
OUTPUT SWITCH SECTION						
$V_{SAT\ 1}$	Output Saturation Voltage 1	I_{SW} = 1.0A (*Figure 1*)		1.1	1.3	V
$V_{SAT\ 2}$	Output Saturation Voltage 2	I_{SW} = 1.0A (*Figure 2*)		0.45	0.7	V

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Electrical Characteristics (Note 5) (Continued)

T_A = Operating temperature range, V_{IN} = 5.0V, V^+(Op Amp) = 5.0V, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
OUTPUT SWITCH SECTION						
h_{FE}	Output Transistor Current Gain	I_C = 1.0A, V_{CE} = 5.0V, T_A = 25˚C		70		
I_L	Output Leakage Current	V_O = 40V, T_A = 25˚C		10		nA
POWER DIODE						
V_{FD}	Forward Voltage Drop	I_D = 1.0A		1.25	1.5	V
I_{DR}	Diode Leakage Current	V_D = 40V, T_A = 25˚C		10		nA
COMPARATOR						
V_{IO}	Input Offset Voltage	V_{CM} = V_{REF}		1.5	15	mV
I_{IB}	Input Bias Current	V_{CM} = V_{REF}		35	200	nA
I_{IO}	Input Offset Current	V_{CM} = V_{REF}		5.0	75	nA
V_{CM}	Common Mode Voltage Range	T_A = 25˚C	0		V_{IN}–2	V
PSRR	Power Supply Rejection Ratio	V_{IN} = 3.0V to 40V, T_A = 25˚C	70	96		dB
OPERATIONAL AMPLIFIER						
V_{IO}	Input Offset Voltage	V_{CM} = 2.5V		4.0	15	mV
I_{IB}	Input Bias Current	V_{CM} = 2.5V		30	200	nA
I_{IO}	Input Offset Current	V_{CM} = 2.5V		5.0	75	nA
A_{VS}^+	Voltage Gain$^+$	R_L = 2.0 kΩ to GND; V_O = 1.0V to 2.5V, T_A = 25˚C	25	250		V/mV
A_{VS}^-	Voltage Gain$^-$	R_L = 2.0 kΩ to V^+ (Op Amp) V_O = 1.0V to 2.5V, T_A = 25˚C	25	250		V/mV
V_{CM}	Common Mode Voltage Range	T_A = 25˚C	0		V_{CC} – 2	V
CMR	Common Mode Rejection	V_{CM} = 0V to 3.0V, T_A = 25˚C	76	100		dB
PSRR	Power Supply Rejection Ratio	V^+ (Op Amp) = 3.0V to 40V, T_A = 25˚C	76	100		dB
I_O^+	Output Source Current	T_A = 25˚C	75	150		mA
I_O^-	Output Sink Current	T_A = 25˚C	10	35		mA
SR	Slew Rate	T_A = 25˚C		0.6		V/µs
V_{OL}	Output Voltage LOW	I_L = –5.0 mA, T_A = 25˚C			1.0	V
V_{OH}	Output Voltage High	I_L = 50 mA, T_A = 25˚C	V + (Op Amp) – 3V			V

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Electrical specifications do not apply when ordering the device beyond its rated operating conditions.

Note 2: $T_{J\ Max}$ = 150˚C for the Molded DIP, and 175˚C for the Ceramic DIP.

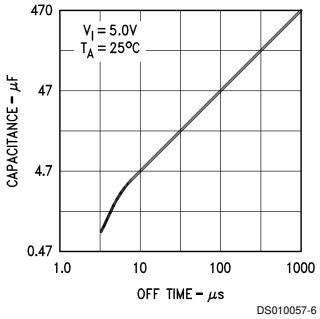
Note 3: Ratings apply to ambient temperature at 25˚C. Above this temperature, derate the 16L-Ceramic DIP at 10 mW/˚C, and the 16L-Molded DIP at 8.3 mW/˚C.

Note 4: For supply voltages less than 30V, the absolute maximum voltage is equal to the supply voltage.

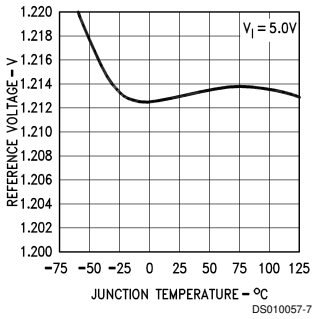
Note 5: A military RETS specification is available on request. At the time of printing, the LM78S40 RETS specification complied with the Min and Max limits in this table. The LM78S40J may also be procured as a Standard Military Drawing.

Typical Performance Characteristics

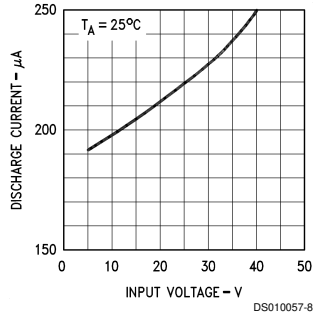
C_T vs OFF Time



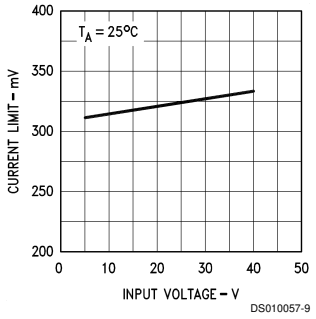
Reference Voltage vs Junction Temperature



Discharge Current vs Input Voltage



Current Limit Sense Voltage vs Input Voltage



Design Formulas

Characteristic	Step-Down	Step-Up	Inverting	Units
$\frac{t_{on}}{t_{off}}$	$\frac{V_O + V_D}{V_I - V_{SAT} - V_O}$	$\frac{V_O + V_D - V_I}{V_I - V_{SAT}}$	$\frac{\lvert V_O \rvert + V_D}{V_I - V_{SAT}}$	
$(t_{on} + t_{off})$ Max	$\frac{1}{f_{Min}}$	$\frac{1}{f_{Min}}$	$\frac{1}{f_{MIN}}$	µs
C_T	$4 \times 10^{-5}\ t_{on}$	$4 \times 10^{-5}\ t_{on}$	$4 \times 10^{-5}\ t_{on}$	µF
I_{pk}	$2\ I_{O\ Max}$	$2\ I_{O\ Max} \bullet \frac{t_{on} + t_{off}}{t_{off}}$	$2\ I_{O\ Max} \bullet \frac{t_{on} + t_{off}}{t_{off}}$	A
L_{Min}	$\left(\frac{V_I - V_{SAT} - V_O}{I_{pk}}\right) t_{on\ Max}$	$\left(\frac{V_I - V_{SAT}}{I_{pk}}\right) t_{on\ Max}$	$\left(\frac{V_I - V_{SAT}}{I_{pk}}\right) t_{on\ Max}$	µH
R_{SC}	$0.33/I_{pk}$	$0.33/I_{pk}$	$0.33/I_{pk}$	Ω
C_O	$\frac{I_{pk}\ (t_{on} + t_{off})}{8\ V_{ripple}}$	$\approx \frac{I_O}{V_{ripple}} \bullet t_{on}$	$\approx \frac{I_O}{V_{ripple}} \bullet t_{on}$	µF

Note 6: V_{SAT} = Saturation voltage of the switching element.

V_D = Forward voltage of the flyback diode.

Functional Description

SWITCHING FREQUENCY CONTROL

The LM78S40 is a variable frequency, variable duty cycle device. The initial switching frequency is set by the timing capacitor. (Oscillator frequency is set by a single external capacitor and may be varied over a range of 100 Hz to 100 kHz). The initial duty cycle is 6:1. This switching frequency and duty cycle can be modified by two mechanisms — the current limit circuitry ($I_{pk\ sense}$) and the comparator.

The comparator modifies the OFF time. When the output voltage is correct, the comparator output is in the HIGH state and has no effect on the circuit operation. If the output voltage is too high then the comparator output goes LOW. In the LOW state the comparator inhibits the turn-on of the output stage switching transistors. As long as the comparator is LOW the system is in OFF time. As the output current rises the OFF time decreases. As the output current nears its maximum the OFF time approaches its minimum value. The comparator can inhibit several ON cycles, one ON cycle or any portion of an ON cycle. Once the ON cycle has begun the comparator cannot inhibit until the beginning of the next ON cycle.

The current limit modifies the ON time. The current limit is activated when a 300 mV potential appears between lead 13 (V_{CC}) and lead 14 (I_{pk}). This potential is intended to result when designed for peak current flows through R_{SC}. When the peak current is reached the current limit is turned on. The current limit circuitry provides for a quick end to ON time and the immediate start of OFF time.

Generally the oscillator is free running but the current limit action tends to reset the timing cycle.

Increasing load results in more current limited ON time and less OFF time. The switching frequency increases with load current.

USING THE INTERNAL REFERENCE, DIODE, AND SWITCH

The internal 1.245V reference (pin 8) must be bypassed, with 0.1 µF directly to the ground pin (pin 11) of the LM78S40, to assure its stability.

V_{FD} is the forward voltage drop across the internal power diode. It is listed on the data sheet as 1.25V typical, 1.5V maximum. If an external diode is used, then its own forward voltage drop must be used for V_{FD}.

V_{SAT} is the voltage across the switch element (output transistors Q1 and Q2) when the switch is closed or ON. This is listed on the data sheet as Output Saturation Voltage.

"Output saturation voltage 1" is defined as the switching element voltage for Q2 and Q1 in the Darlington configuration with collectors tied together. This applies to *Figure 1*, the step down mode.

"Output saturation voltage 2" is the switching element voltage for Q1 only when used as a transistor switch. This applies to *Figure 2*, the step up mode.

For the inverting mode, *Figure 3*, the saturation voltage of the external transistor should be used for V_{SAT}.

Typical Applications

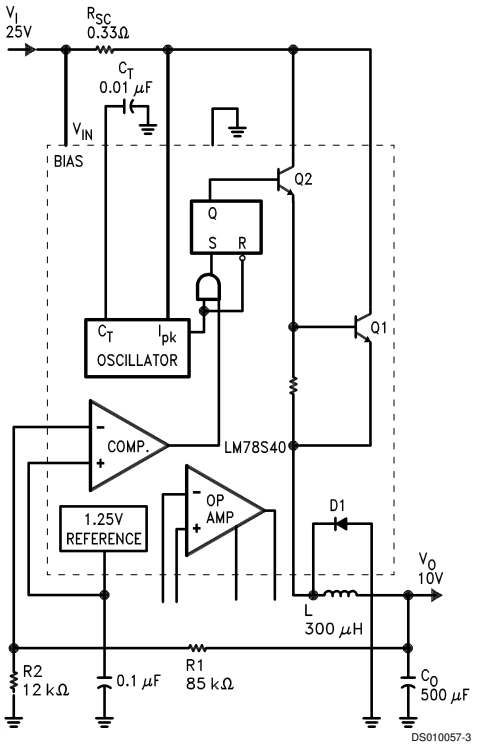


FIGURE 1. Typical Step-Down Regulator and Operational Performance (T_A = 25˚C)

Characteristic	Condition	Typical Value
Output Voltage	I_O = 200 mA	10V
Line Regulation	20V ≤ V_I ≤ 30V	1.5 mV
Load Regulation	5.0 mA ≤ I_O ≤ 300 mA	3.0 mV
Max Output Current	V_O = 9.5V	500 mA
Output Ripple	I_O = 200 mA	50 mV
Efficiency	I_O = 200 mA	74%
Standby Current	I_O = 200 mA	2.8 mA

Note 7: For $I_O \geq$ 200 mA use external diode to limit on-chip power dissipation.

Typical Applications (Continued)

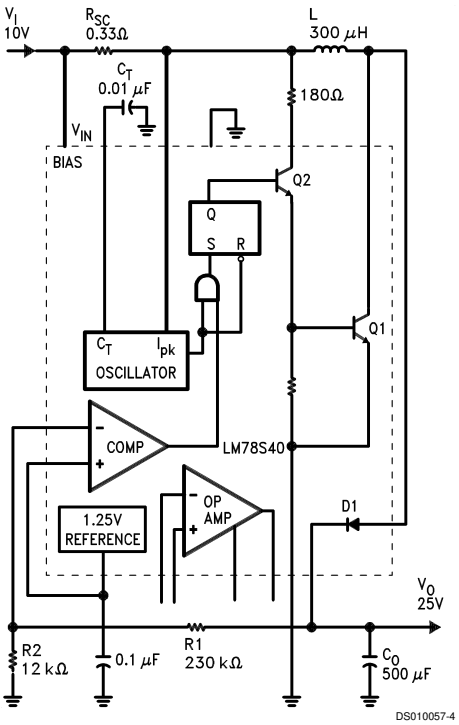


FIGURE 2. Typical Step-Up Regulator and Operational Performance (T_A = 25˚C)

Characteristic	Condition	Typical Value
Output Voltage	I_O = 50 mA	25V
Line Regulation	5.0V ≤ V_I ≤ 15V	4.0 mV
Load Regulation	5.0 mA ≤ I_O I_O ≤ 100 mA	2.0 mV
Max Output Current	V_O = 23.75V	160 mA
Output Ripple	I_O = 50 mA	30 mV
Efficiency	I_O = 50 mA	79%
Standby Current	I_O = 50 mA	2.6 mA

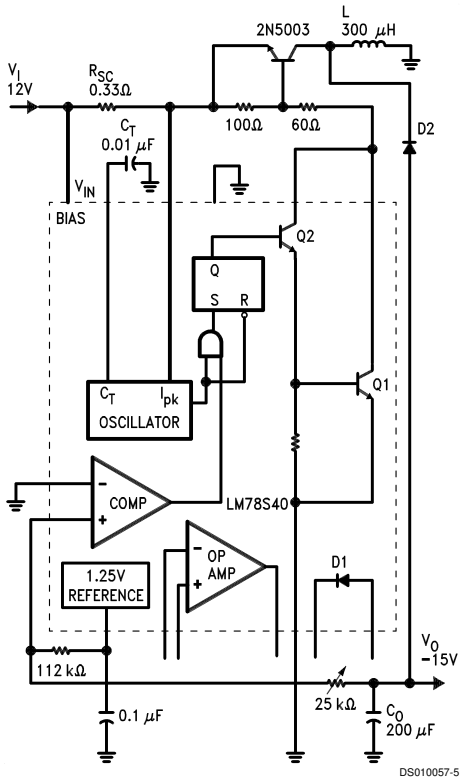


FIGURE 3. Typical Inverting Regulator and Operational Performance (T_A = 25˚C)

Characteristic	Condition	Typical Value
Output Voltage	I_O = 100 mA	−15V
Line Regulation	8.0V ≤ V_I ≤ 18V	5.0 mV
Load Regulation	5.0 mA ≤ I_O I_O ≤ 150 mA	3.0 mV
Max Output Current	V_O = 14.25V	160 mA
Output Ripple	I_O = 100 mA	20 mV
Efficiency	I_O = 100 mA	70%
Standby Current	I_O = 100 mA	2.3 mA

Typical Applications (Continued)

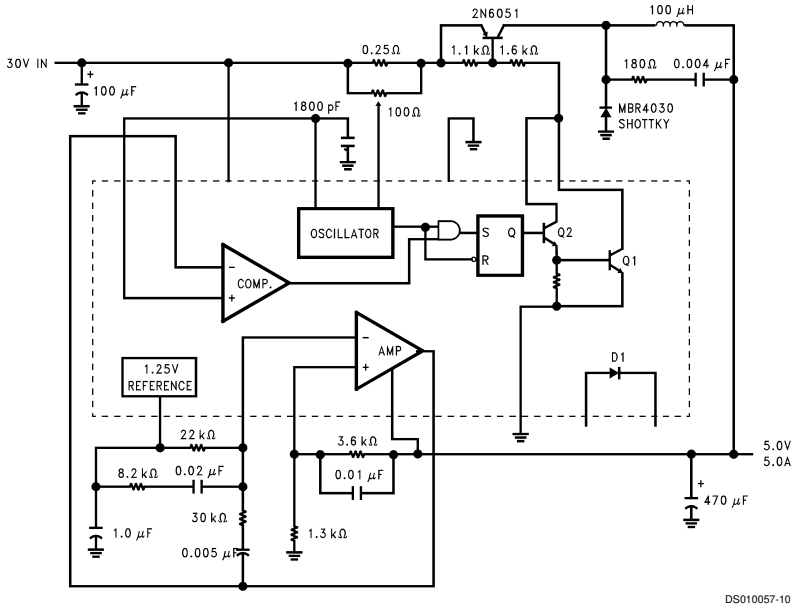


FIGURE 4. Pulse Width Modulated Step-Down Regulator (f_{OSC} = 20 kHz)

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM78S40CN/NOPB	Active	Production	PDIP (NFG) | 16	25 | TUBE	Yes	SN	Level-1-NA-UNLIM	0 to 70	LM78S40CN
LM78S40CN/NOPB.Z	Active	Production	PDIP (NFG) | 16	25 | TUBE	Yes	SN	Level-1-NA-UNLIM	0 to 70	LM78S40CN

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

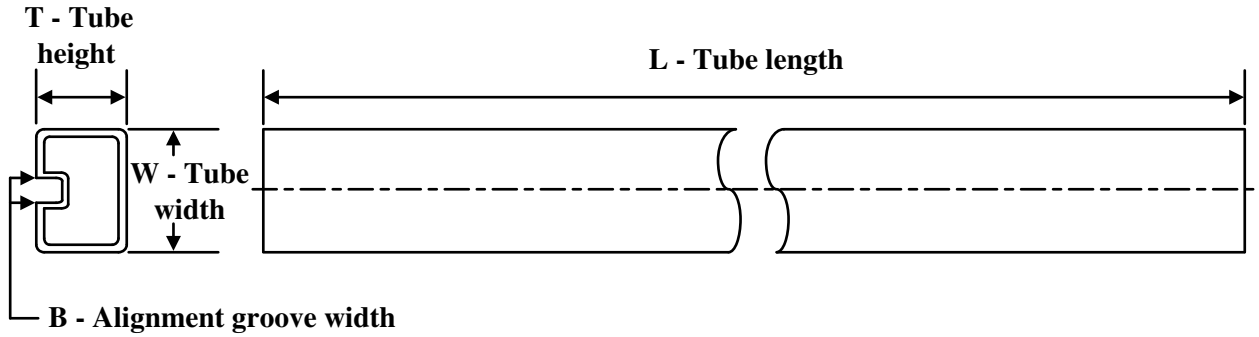
(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

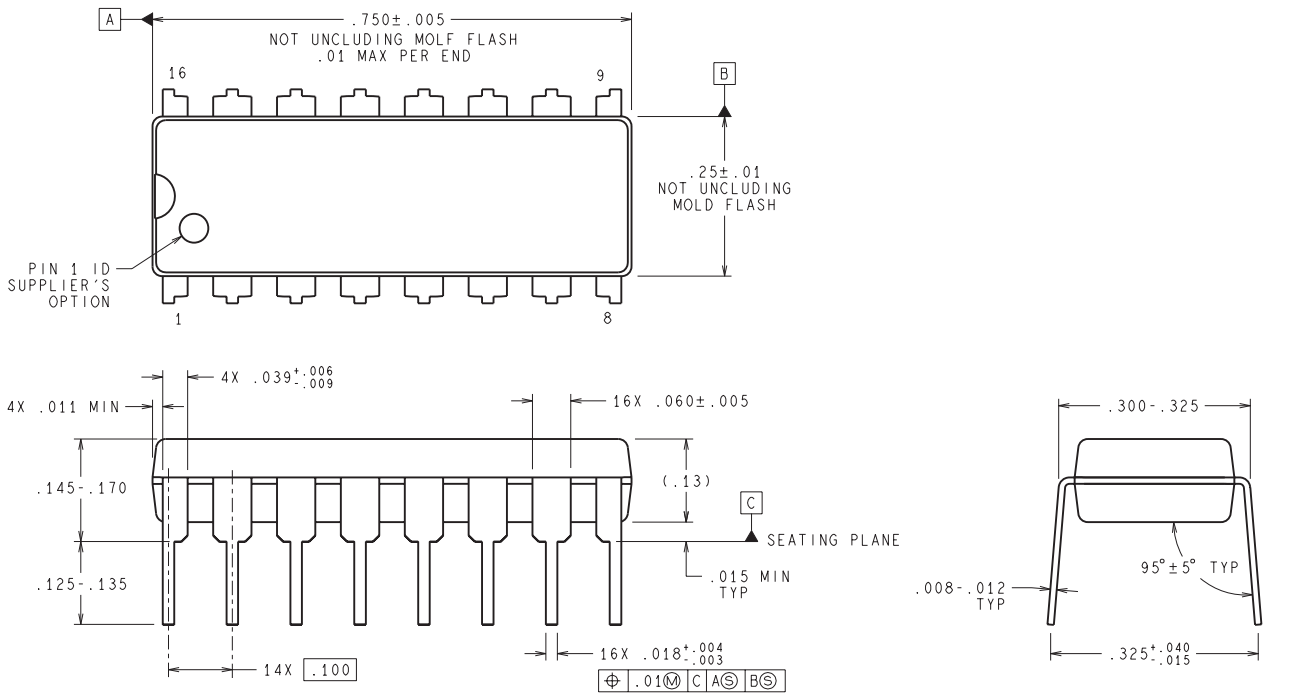
TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
LM78S40CN/NOPB	NFG	PDIP	16	25	502	14	11938	4.32
LM78S40CN/NOPB.Z	NFG	PDIP	16	25	502	14	11938	4.32

NFG0016E



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